Superior high Flux for High Voltage System

Acrich MJT-5050 Series

SAW8L60A (Cool, Neutral, Warm)









Product Brief

Description

- This White Colored surface-mount LED comes in standard package dimension.
 Package Size: 5.0x5.0x0.70mm
- The MJT series of LEDs are designed for AC & DC(High Voltage) operation and high flux output applications.
- The MJT is ideal light sources for general illumination applications and custom designed solutions
- The package design coupled with careful selection of component materials allow these products to perform with high reliability

Features and Benefits

- High Intensity output and high luminance
- Designed for high voltage operation
- High Color Quality with CRI Min.80
- SMT solderable
- RoHS compliant

Key Applications

- General lighting
- Architectural lighting
- LED Bulbs
- · Decorative / Pathway lighting

Table 1. Product Selection Table

Part Number		CRI			
	Color	Min.	Тур.	Max.	CRI
SAW8L60A	Cool White	4700K	5600K	7000K	80
	Neutral White	3700K	4200K	4700K	80
	Warm White	2600K	3000K	3700K	80



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Product Performance & Characterization Guide

Table 2. Product Selection Guide, $I_F = 65mA$, $T_i = 25^{\circ}C$, RH30%

Min. CRI, R _a	Nominal CCT [K] ^[1]	Min. Flux [lm]	Typ. Luminous Flux Φ _v ^[2] [lm] @60mA	Typ. Luminous Efficacy [lm/W] @60mA	PPF ^[3] [µmol/s] @60mA	PPE ^[4] [µmol/J] @60mA
	6500	171	185.9	188	2.701	2.501
	5700	171	190.7	193	2.727	2.525
-	5000	171	193.5	195	2.741	2.538
00	4500	171	194.3	196	2.724	2.523
80	4000	171	197.5	199	2.615	2.421
_	3500	171	189.8	192	2.554	2.364
	3000	171	189.4	191	2.546	2.358
	2700	171	183.7	186	2.525	2.338

Notes:

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Photosynthetic Photon Flux (PPF) includes wavelengths between 400 and 700 nm.
- (4) Photosynthetic Photon Efficacy (PPE) includes wavelengths between 400 and 700 nm.

Product Performance & Characterization Guide

Table 2. Characteristics, I_F=60mA, T_i=25°C

Dovemeter	Cumbal		Value			
Parameter	Symbol	Min.	Тур.	Max.	Unit	
Forward Voltage	V_{F}	15.0	16.5	18.0	V	
Luminous Flux ^[1] (5000K) ^[3]	♣ [2]	-	187	-	l.e.	
Luminous Flux ^[1] (3000K) ^[3]	- Φ _ν ^[2]	-	182	-	lm	
Correlated Color Temperature ^[3]	CCT	2,700	-	7,000	К	
CRI ^[4]	Ra	80	-	90	-	
Viewing Angle	2Θ1/2	-	120	-	deg.	
Thermal resistance (J to S) ^[5]	Rθ _{j-s}	-	1.8	-	K/W	
ESD Sensitivity(HBM) [6]	-		Class2 JESD	22-A114E		

Table 3. Electro-Optical Characteristics, T_i=25°C, CCT=5000K

I _F [mA]	∨ _F [V]	Power [W]	$\Phi_{_{ m V}}$ [lm]	Efficacy [lm/W]
60	16.5	1.0	187	189
220	18.0	4.0	638	161
320	18.9	6.0	893	148

Table 4. Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	l _F	10 320	mA
Power Dissipation	P_{D}	6.0	W
Junction Temperature	T _j	125	°C
Operating Temperature	T_{opr}	-40 ~ + 100	°C
Storage Temperature	T _{stg}	-40 ~ + 100	°C

Notes:

- (1) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (2) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (3) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate: ±0.005, CCT ±5% tolerance.
- (4) Tolerance is ± 2.0 on CRI measurements.
- (5) Thermal resistance: Rth_{JS} (Junction to Solder)
- Calculated performance values are for reference only.
- All measurements were made under the standardized environment of Seoul Semiconductor.
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.

Fig 1. Color Spectrum, T_i=25°C, I_F=60mA (CRI80)

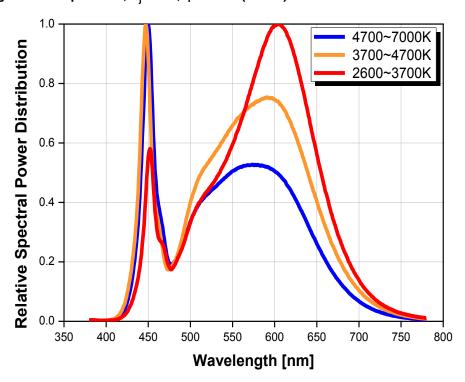


Fig 2. Radiant pattern, T_i=25°C, I_F=60mA

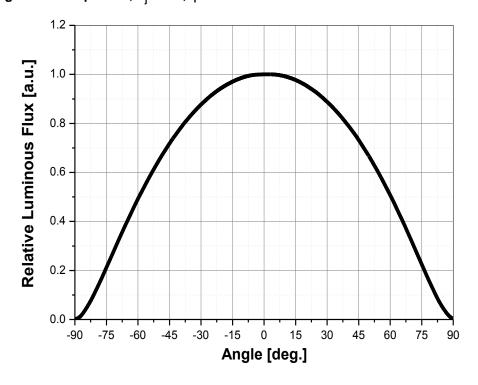


Fig 3. Forward Voltage vs. Forward Current, T_i=25°C

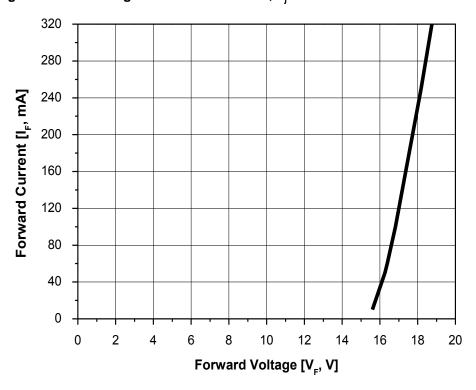


Fig 4. Forward Current vs. Relative Luminous Flux, T_i=25°C

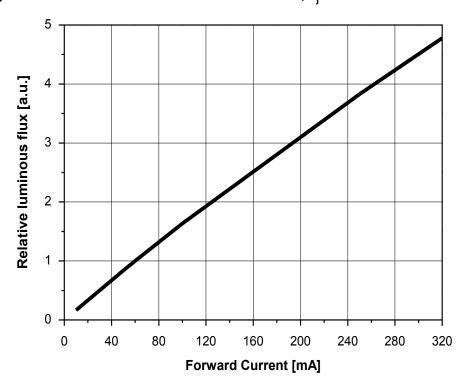
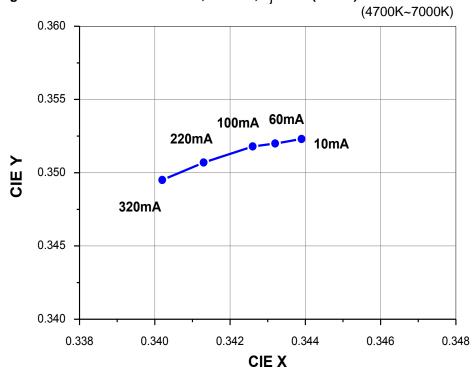


Fig 5. Forward Current vs. CIE X, Y Shift , T_i=25°C (CRI80)



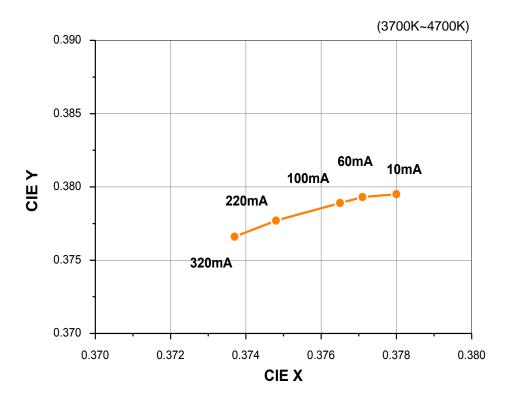


Fig 5. Forward Current vs. CIE X, Y Shift , T_i=25°C (CRI80)

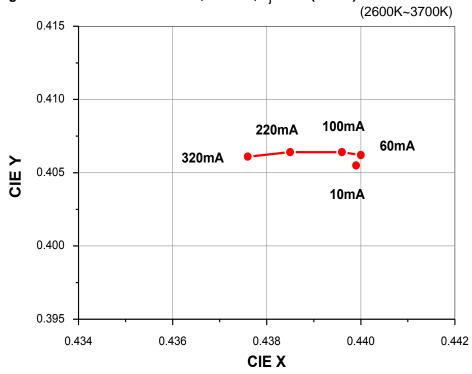


Fig 6. Relative Light Output vs. Junction Temperature, I_F=60mA

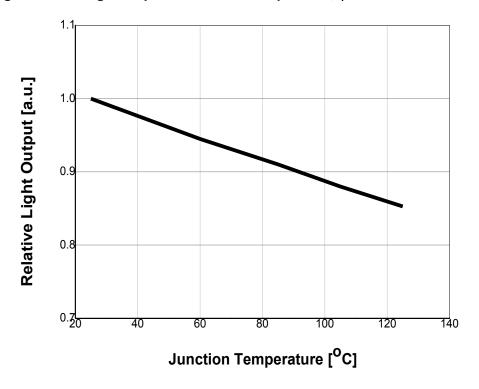


Fig 7. Relative Forward Voltage vs. Junction Temperature, I_F=60mA

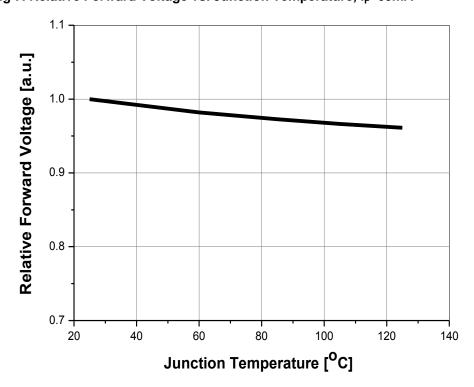
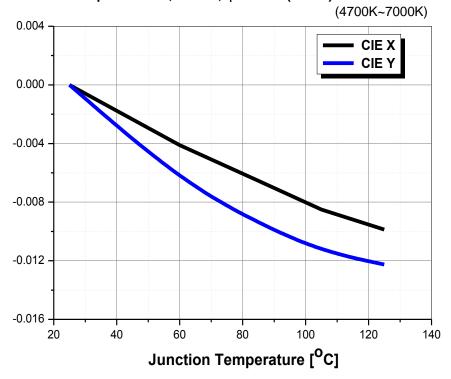


Fig 8. Junction Temp. vs. CIE X, Y Shift, I_F=60mA (CRI80)



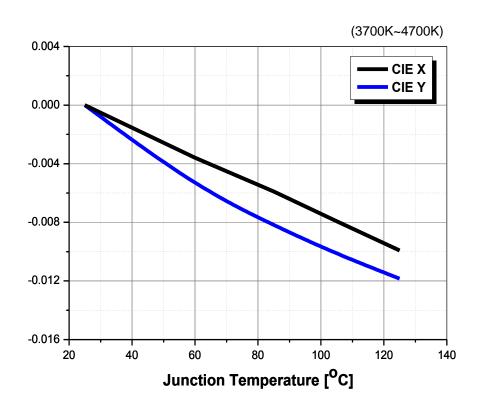


Fig 8. Junction Temp. vs. CIE X, Y Shift, I_E=60mA (CRI80)

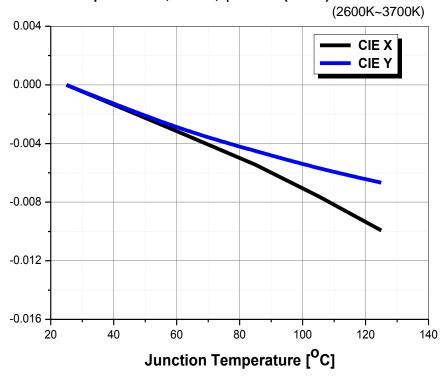
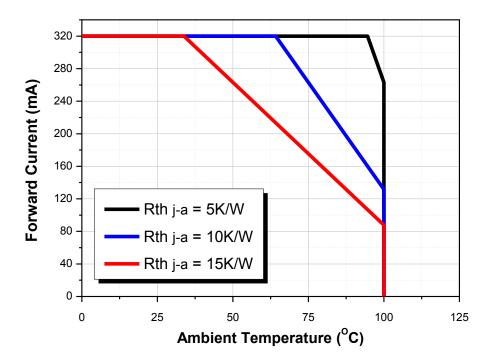


Fig 9. Maximum Forward Current vs. Ambient Temperature, T_i(max.)=125°C, I_F=320mA



Color Bin Structure

Table 5. Bin Code description, T_i=25°C, I_F=60mA

Part Number	Luminous Flux (lm) I _F =60mA		Color Chromaticity	Forward Voltage (V _f) I _F =60mA			
	Bin Code	Min.	Max.	Coordinate	Bin Code	Min.	Max.
	W1	155	171	Refer to	Z	15.0	16.0
SAW8L60A	W2	171	186		Α	16.0	17.0
	X1	186	202		В	17.0	18.0

Table 6. Luminous Flux rank distribution

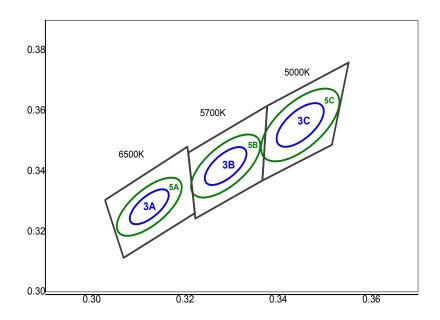
ССТ	CIE		Flux Rank	
7000 ~ 6000K	А	W1	W2	X1
6000 ~ 5300K	В	W1	W2	X1
5300 ~ 4700K	С	W1	W2	X1
4700 ~ 4200K	D	W1	W2	X1
4200 ~ 3700K	Е	W1	W2	X1
3700 ~ 3200K	F	W1	W2	X1
3200 ~ 2900K	G	W1	W2	X1
2900 ~ 2600K	Н	W1	W2	X1

Available ranks
Not yet available ranks

• All measurements were made under the standardized environment of Seoul Semiconductor.

Color Bin Structure

CIE Chromaticity Diagram (Cool white), T_j =25°C, I_F =60mA

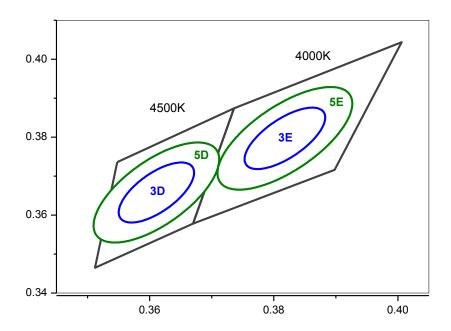


6500	K 3Step	5700	K 3Step	5000	K 3Step
	3A	3B		3B 3C	
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553
Major Axis a	0.0066	Major Axis a	0.0071	Major Axis a	0.0081
Minor Axis b	0.0027	Minor Axis b	0.003	Minor Axis b	0.0035
Ellipse	58	Ellipse	59	Ellipse	60
Rotation Angle	50	Rotation Angle	39	Rotation Angle	00

6500	K 5Step	5700K 5Step		5000K 5Step	
	5A		5B		5C
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553
Major Axis a	0.0110	Major Axis a	0.0118	Major Axis a	0.0135
Minor Axis b	0.0045	Minor Axis b	0.0050	Minor Axis b	0.0058
Ellipse	58	Ellipse	59	Ellipse	60
Rotation Angle	50	Rotation Angle	59	Rotation Angle	00

Color Bin Structure

CIE Chromaticity Diagram (Neutral white), T_i=25°C, I_F=60mA



4500K 3Step

4000K 3Step

3E				
Center point	0.3818 : 0.3797			
Major Axis a	0.00940			
Minor Axis b	0.00400			
Ellipse Rotation Angle	53			

4500K 5Step

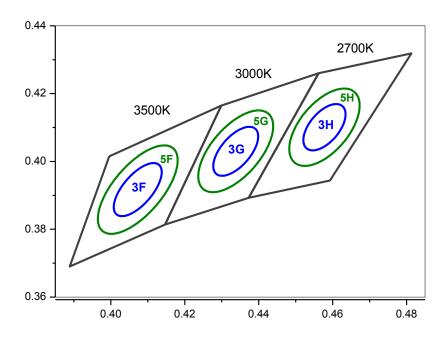
		5D		
Cent	er point	0.3611 : 0.3658		
Majo	r Axis a	0.0150		
Mino	r Axis b	0.0065		
EI	lipse	E E		
Rotati	on Angle	55		

4000K 5Step

100011 0000		
51	E	
Center point	0.3818 : 0.3797	
Major Axis a	0.0157	
Minor Axis b	0.0067	
Ellipse	53	
Rotation Angle	53	

Color Bin Structure

CIE Chromaticity Diagram (Warm white), T_i=25°C, I_F=60mA

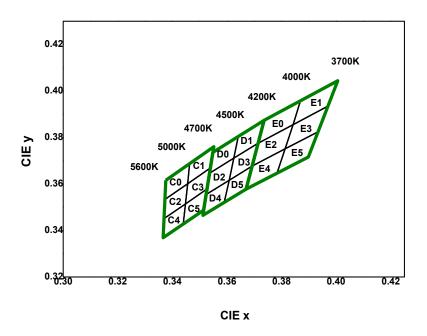


3500K 3Step 3000K 3Step		K 3Step	2700	K 3Step		
	3F 3G		3F			3H
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101	
Major Axis a	0.0093	Major Axis a	0.0085	Major Axis a	0.0079	
Minor Axis b	0.0041	Minor Axis b	0.0041	Minor Axis b	0.0041	
Ellipse	53	Ellipse	53	Ellipse	 54	
Rotation Angle	J.S	Rotation Angle	J3	Rotation Angle	J 4	

3500	3500K 5Step 3000K 5Step		2700K 5Step		
	5F		5G		5H
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101
Major Axis a	0.0155	Major Axis a	0.0142	Major Axis a	0.0132
Minor Axis b	0.0068	Minor Axis b	0.0068	Minor Axis b	0.0068
Ellipse Rotation Angle	53	Ellipse Rotation Angle	53	Ellipse Rotation Angle	54

Color Bin Structure

CIE Chromaticity Diagram, $T_j=25$ °C, $I_F=60$ mA



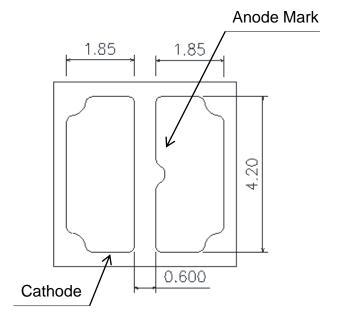
	C0	C	1	C	:2
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3376	0.3616	0.3463	0.3687	0.3373	0.3534
0.3373	0.3534	0.3456	0.3601	0.3369	0.3451
0.3456	0.3601	0.3539	0.3669	0.3448	0.3514
0.3463	0.3687	0.3552	0.3760	0.3456	0.3601
	C3	C	4	С	5
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3456	0.3601	0.3369	0.3451	0.3448	0.3514
0.3448	0.3514	0.3366	0.3369	0.3440	0.3428
0.3526	0.3578	0.3440	0.3428	0.3514	0.3487
0.3539	0.3669	0.3448	0.3514	0.3526	0.3578
	D 0	D		D	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3548	0.3736	0.3641	0.3804	0.3536	0.3646
0.3536	0.3646	0.3625	0.3711	0.3524	0.3555
0.3625	0.3711	0.3714	0.3775	0.3608	0.3616
0.3641	0.3804	0.3736	0.3874	0.3625	0.3711
	D3	D	4	D	5
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3625	0.3711	0.3524	0.3555	0.3608	0.3616
0.3625 0.3608	0.3711 0.3616	0.3524 0.3512	0.3555 0.3465	0.3608 0.3590	0.3616 0.3521
0.3625 0.3608 0.3692	0.3711 0.3616 0.3677	0.3524 0.3512 0.3590	0.3555 0.3465 0.3521	0.3608 0.3590 0.3670	0.3616 0.3521 0.3578
0.3625 0.3608 0.3692 0.3714	0.3711 0.3616 0.3677 0.3775	0.3524 0.3512 0.3590 0.3608	0.3555 0.3465 0.3521 0.3616	0.3608 0.3590 0.3670 0.3692	0.3616 0.3521 0.3578 0.3677
0.3625 0.3608 0.3692 0.3714	0.3711 0.3616 0.3677 0.3775	0.3524 0.3512 0.3590 0.3608	0.3555 0.3465 0.3521 0.3616	0.3608 0.3590 0.3670 0.3692	0.3616 0.3521 0.3578 0.3677
0.3625 0.3608 0.3692 0.3714	0.3711 0.3616 0.3677 0.3775 E0	0.3524 0.3512 0.3590 0.3608 E	0.3555 0.3465 0.3521 0.3616	0.3608 0.3590 0.3670 0.3692 E	0.3616 0.3521 0.3578 0.3677 2 CIE y
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736	0.3711 0.3616 0.3677 0.3775 E0 CIE y 0.3874	0.3524 0.3512 0.3590 0.3608 E CIE x 0.3869	0.3555 0.3465 0.3521 0.3616 11 CIE y 0.3958	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736 0.3714	0.3711 0.3616 0.3677 0.3775 E0 CIE y 0.3874 0.3775	0.3524 0.3512 0.3590 0.3608 E CIE x 0.3869 0.3842	0.3555 0.3465 0.3521 0.3616 11 CIE y 0.3958 0.3855	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714 0.3692	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775 0.3677
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736 0.3714 0.3842	0.3711 0.3616 0.3677 0.3775 E0 CIE y 0.3874 0.3775 0.3855	0.3524 0.3512 0.3590 0.3608 E CIE x 0.3869 0.3842 0.3970	0.3555 0.3465 0.3521 0.3616 11 CIE y 0.3958 0.3855 0.3935	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714 0.3692 0.3813	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775 0.3677 0.3751
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736 0.3714 0.3842 0.3869	0.3711 0.3616 0.3677 0.3775 E0 CIE y 0.3874 0.3775 0.3855 0.3958	0.3524 0.3512 0.3590 0.3608 E CIE x 0.3869 0.3842 0.3970 0.4006	0.3555 0.3465 0.3521 0.3616 11 CIE y 0.3958 0.3855 0.3935 0.4044	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714 0.3692 0.3813 0.3842	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775 0.3677 0.3751 0.3855
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736 0.3714 0.3842 0.3869	0.3711 0.3616 0.3677 0.3775 E0 CIE y 0.3874 0.3775 0.3855 0.3958	0.3524 0.3512 0.3590 0.3608 E CIE x 0.3869 0.3842 0.3970 0.4006	0.3555 0.3465 0.3521 0.3616 11 CIE y 0.3958 0.3855 0.3935 0.4044	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714 0.3692 0.3813 0.3842	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775 0.3677 0.3751 0.3855
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736 0.3714 0.3842 0.3869	0.3711 0.3616 0.3677 0.3775 E0 CIE y 0.3874 0.3775 0.3855 0.3958 E3 CIE y	0.3524 0.3512 0.3590 0.3608 E CIE x 0.3869 0.3842 0.3970 0.4006	0.3555 0.3465 0.3521 0.3616 11 CIE y 0.3958 0.3855 0.3935 0.4044 CIE y	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714 0.3692 0.3813 0.3842 E CIE x	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775 0.3677 0.3751 0.3855 5 CIE y
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736 0.3714 0.3842 0.3869 CIE x 0.3842	0.3711 0.3616 0.3677 0.3775 E0 CIE y 0.3874 0.3775 0.3855 0.3958 E3 CIE y 0.3855	0.3524 0.3512 0.3590 0.3608 CIE x 0.3869 0.3842 0.3970 0.4006 CIE x 0.3692	0.3555 0.3465 0.3521 0.3616 11 CIE y 0.3958 0.3855 0.3935 0.4044 CIE y 0.3677	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714 0.3692 0.3813 0.3842 E CIE x 0.3813	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775 0.3677 0.3751 0.3855 5 CIE y 0.3751
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736 0.3714 0.3842 0.3869 CIE x 0.3842 0.3842	0.3711 0.3616 0.3677 0.3775 CIE y 0.3874 0.3775 0.3855 0.3958 CIE y 0.3855 0.3751	0.3524 0.3512 0.3590 0.3608 CIE x 0.3869 0.3842 0.3970 0.4006 CIE x 0.3692 0.3670	0.3555 0.3465 0.3521 0.3616 1 CIE y 0.3958 0.3855 0.3935 0.4044 4 CIE y 0.3677 0.3578	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714 0.3692 0.3813 0.3842 E CIE x 0.3813 0.3783	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775 0.3677 0.3751 0.3855 5 CIE y 0.3751 0.3646
0.3625 0.3608 0.3692 0.3714 CIE x 0.3736 0.3714 0.3842 0.3869 CIE x 0.3842	0.3711 0.3616 0.3677 0.3775 E0 CIE y 0.3874 0.3775 0.3855 0.3958 E3 CIE y 0.3855	0.3524 0.3512 0.3590 0.3608 CIE x 0.3869 0.3842 0.3970 0.4006 CIE x 0.3692	0.3555 0.3465 0.3521 0.3616 11 CIE y 0.3958 0.3855 0.3935 0.4044 CIE y 0.3677	0.3608 0.3590 0.3670 0.3692 E CIE x 0.3714 0.3692 0.3813 0.3842 E CIE x 0.3813	0.3616 0.3521 0.3578 0.3677 2 CIE y 0.3775 0.3677 0.3751 0.3855 5 CIE y 0.3751

Mechanical Dimensions

< Top View >

5.00 Cathode Mark

< Bottom View >



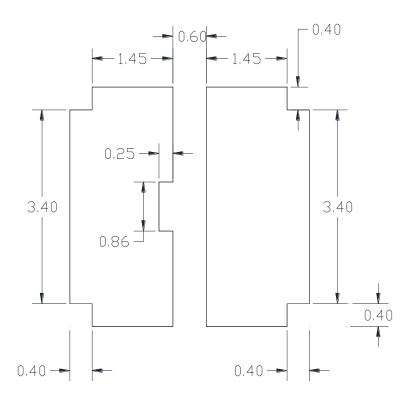
< Side view>

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Notes:

- (1) All dimensions are in millimeters.
- (2) Scale: none
- (3) Undefined tolerance is ± 0.2 mm

Recommended Solder Pad



Notes:

- (1) All dimensions are in millimeters.
- (2) Scale: none
- (3) Undefined tolerance is ± 0.2 mm
- (4) This drawing without tolerances are for reference only.

Reflow Soldering Characteristics

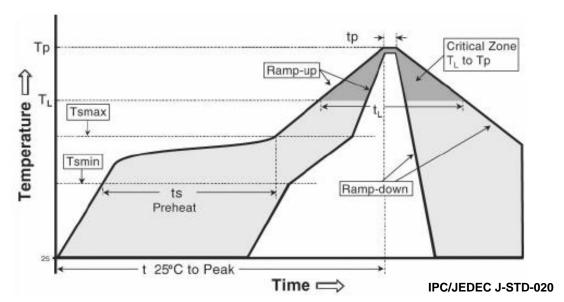


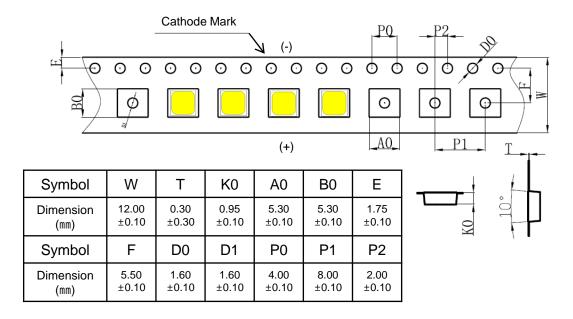
Table 7.

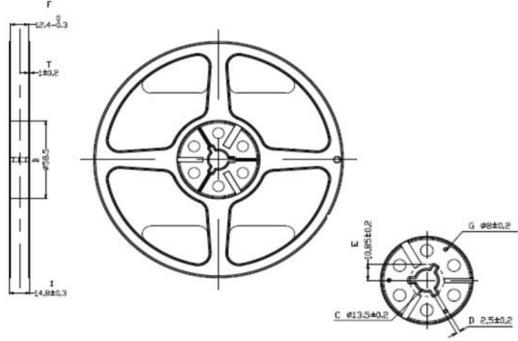
Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T _{smax} to T _p)	3° C/second max.	3° C/second max.
Preheat - Temperature Min (T _{smin}) - Temperature Max (T _{smax}) - Time (T _{smin} to T _{smax}) (t _s)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (T _L) - Time (t _L)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (T _p)	215℃	260℃
Time within 5°C of actual Peak Temperature (t _p)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.

Emitter Tape & Reel Packaging





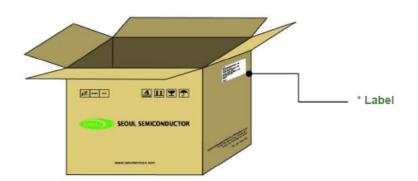
Notes:

- (1) Quantity : 7 inch reel type (1,000 pcs / Reel \pm 1pcs)
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be $\pm 0.2 \text{mm}$
- (3) Adhesion Strength of Cover Tape: Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape
- (4) Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package.

Emitter Tape & Reel Packaging







Product Nomenclature

Table 8. Part Numbering System : $X_1X_2X_3X_4X_5X_6X_7X_8$

Part Number Code	Description	Part Number	Value
X ₁	Company	S	SSC
X ₂	Acrich LED series	А	Acrich LED
X ₃ X ₄	Color Specification	W8	CRI80
X ₅	Package series	L	L series
X ₆	Chip	6	6 series
X ₇	PCB type	0	Emitter
X ₈	Revision	А	rev0

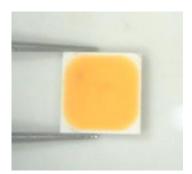
Table 9. Lot Numbering System :Y₁Y₂Y₃Y₄Y₅Y₆Y₇Y₈Y₉Y₁₀-Y₁₁Y₁₂Y₁₃Y₁₄Y₁₅Y₁₆Y₁₇

Lot Number Code	Description	Lot Number	Value
Y ₁ Y ₂	Year		
Y ₃	Month		
Y ₄ Y ₅	Day		
Y ₆	Top View LED series		
Y ₇ Y ₈ Y ₉ Y ₁₀	Mass order		
Y ₁₁ Y ₁₂ Y ₁₃ Y ₁₄ Y ₁₅ Y ₁₆ Y ₁₇	Internal Number		

Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.





- (2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.
- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

- (5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin.

 Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.
- (6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this. product with acid or sulfur material in sealed space.

Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend store in a dry box with a desiccant. The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use SMT techniques properly when you solder the LED as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 40°C Humidity : less than RH30%
- b. If the package has been opened more than 4 week(MSL_2a) or the color of the desiccant changes, components should be dried for 10-12hr at $60\pm5^{\circ}$ C
- (3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
- (4) Do not rapidly cool device after soldering.
- (5) Components should not be mounted on warped (non coplanar) portion of PCB.
- (6) Radioactive exposure is not considered for the products listed here in.
- (7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
- (8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.
- (9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.
- (10) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from Seoul Semiconductor. A sealed container with a nitrogen atmosphere should be used for storage.
- (11) The appearance and specifications of the product may be modified for improvement without notice.
- (12) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

Precaution for Use

- (13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (14) The slug is electrically isolated.
- (15) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (16) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.
- (17) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.
- a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)

Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
 (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.
- c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:
 - A surge protection circuit
 - An appropriately rated over voltage protection device
 - A current limiting device

Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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